


TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

Title of Invention	METHOD OF FABRICATING A CMOS DEVICE WITH DUAL METAL GATE ELECTRODES	
Application Number : Date : First Named Applicant: Confirmation Number: Attorney Docket Number:	10/826665 2004-04-16 PARK CHANG SEO 9608 61472-0308425	
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Submitted By: DAVID H. JAFFER Registered Number: 32,243		Elec. Sign. /David H. Jaffer/ Sign. Capacity Attorney

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